

Surface plasmons at composite surfaces with diffusive charges

Baruch Horovitz¹ and Carsten Henkel²

¹ *Department of Physics, Ben Gurion University, Beer Sheva 84105, Israel and*

² *Institut für Physik und Astronomie, Universität Potsdam, 14476 Potsdam, Germany*

Metal surfaces with disorder or with nanostructure modifications are studied, allowing for a localized charge layer (CL) in addition to continuous charges (CC) in the bulk, both charges having a compressional or diffusive non-local response. The notorious problem of “additional boundary conditions” is resolved with the help of a Boltzmann equation that involves the scattering between the two charge types. Depending on the strength of this scattering, the oscillating charges can be dominantly CC or CL; the surface plasmon (SP) resonance acquires then a relatively small linewidth, in agreement with a large set of data. With a few parameters our model describes a large variety of SP dispersions corresponding to observed data.

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Introduction. Collective electronic excitations in metal surfaces covered with adsorbates or nanostructures are of significant recent interest. Surface plasmons (SP) are an efficient tool for characterizing such surfaces^{1,2} and can be used as sensitive chemical sensors and biosensors³.

A considerable amount of data on the dispersion of SPs has been accumulated⁴⁻¹⁶ on a variety of metal surfaces, clean, sputtered, or covered with thin films. These composite surfaces indicate the necessity of distinguishing between two types of charge carriers: continuous charges (CC) extending throughout the bulk and a charge layer (CL) of carriers localized at the surface. In fact, photoemission data on some of these surfaces reveals the existence of quantum well states at the surface¹⁷. The two charge types are relevant also for pure metals: in alkali metals the charge extends beyond the neutralizing ions, forming a distinct layer^{6,7}. In Ag a two-component s-d electron system with different surface and bulk charges has been put forward to explain the SP dispersion¹⁸. In some cases a distinct surface band is formed², e.g. as in Be(0001), showing an acoustic plasmon¹⁹. Further motivation for a two-type charge model comes from studies of the anomalous heating of cold ions observed in miniaturized Paul traps, that invoke surface charge fluctuations on the metallic electrodes²⁰⁻²⁴.

Most information about the SP dispersion $\omega(k)$ is available in the non-retarded range $\omega_p/c \ll k \ll k_F$ where k is the momentum parallel to the surface, ω_p is the bulk plasma frequency, c the speed of light, and k_F the Fermi momentum. In this range, the dispersion is parameterized as $\omega(k) = A + Bk + Ck^2$ and the limiting value $A = \omega_p/\sqrt{2}$ is well known (assuming unit background permittivity)²⁵. Considerable insight is gained by Feibelman’s sum rule²⁶ relating the slope B to the centroid of the oscillating charge density profile $\delta n(z)$:

$$B = -\frac{\omega_p}{2\sqrt{2}} \frac{\int dz z \delta n(z)}{\int dz \delta n(z)}. \quad (1)$$

Here the medium is located in the half-space $z \leq 0$, and the onset of the dielectric function due to bulk ions is at $z = 0$. Hence the SP dispersion is negative ($B < 0$) if

the oscillating charge is dominantly located outside the metal ($z > 0$) as in alkali metals^{6,7}, while $B > 0$ if the oscillating charge is dominantly inside. In some cases the coefficient B is small and the quadratic term Ck^2 dominates the dispersion^{4,14,16}, even at the lowest measurable k . From Eq.(1), $B = 0$ is a strong indication for a charge excitation that is highly localized at the surface, $z = 0$.

In the present work we consider a non-local electrodynamic model including both CC and CL, which for small k involves diffusive (or compressional) terms, similar to hydrodynamic models^{1,2}. The presence of two types of charges leads to the situation that the boundary conditions of Maxwell’s equations are not sufficient to solve the problem. The problem has been originally identified by Pekar²⁷, with a variety of “additional boundary conditions” (ABC) proposed over the years²⁸⁻³¹, and compared with experimental data³⁰. In Ref. 32, a model with two charge types, similar to ours, was considered and an ABC was proposed by arguing that dissipated energy is conserved across a boundary. It is known, however, from ABC studies²⁷⁻³¹ that microscopic information must be used, i.e. Maxwell’s equations by themselves are insufficient.

We address here the ABC problem by solving a Boltzmann equation, allowing for impurity scattering in the bulk as well as surface scattering that mixes CC and CL. Note also that the CL allows charge conservation to hold even if the bulk current perpendicular to the surface is locally finite, representing deviations from specular reflection. In this sense the localized charge is a measure of diffuse scattering or disorder at the surface: the scattered bulk current becomes a surface current which is allowed to diffuse along the surface. A key point of our model are the transition rates between the two types of charges that provide a restoring force (plasma oscillation) and damping for the combined charge oscillations. By allowing for bulk and surface impurity scattering, our approach complements traditional band structure theories^{1,2} and provides a unified framework for analyzing SP dispersion and linewidth. The resulting equations involve a few parameters of the poorly known CL and of the surface-bulk charge scattering. We start with discussing the qualita-

tive effect of the surface scattering and then derive the actual SP dispersion, showing a variety of forms corresponding to experimental data.

Qualitative features. Our model implies that the surface scattering that mixes CC and CL enhances the SP linewidth Γ . Hence Γ is relatively small if the charge response is dominantly CC (large positive slope, $B > Ck_1$ with $k_1 = 1 \text{ \AA}^{-1}$ being a typical large momentum) or dominantly CL (large negative slope, $B < -Ck_1$, or small slope, $|B| < 0.1 Ck_1$). Table I shows all the corresponding cases that we are aware of, confirming this trend for small damping. Cases where $0.1 Ck_1 < |B| < Ck_1$ may or may not correspond to dominant CC or CL and a detailed fit of $\omega(k)$ and $\Gamma(k)$ is needed to determine the parameters.

The model and nonlocal electrodynamics. We proceed to define the charges and currents of the model. The bulk medium is located in $z < 0$, and the surface layer in $0 < z < d$. We write $\rho(\mathbf{r})$ and $\rho_s(\mathbf{r})$, respectively, for the charge density in the two regions. We expand the current response, considering small charge gradients

$$\begin{aligned} \frac{1}{\tau} \mathbf{j} + \partial_t \mathbf{j} &= \frac{\omega_p^2}{4\pi} \mathbf{E} - c_b^2 \nabla \rho & z < 0 \\ \frac{1}{\tau_s} \mathbf{j}_s + \partial_t \mathbf{j}_s &= \frac{\omega_s^2}{4\pi} \mathbf{E} - c_s^2 \nabla \rho_s & 0 < z < d. \end{aligned} \quad (2)$$

The equilibrium charge density provides restoring forces $\omega_p^2/4\pi$ and $\omega_s^2/4\pi$ in the bulk and surface regions, where $\omega_{p,s}$ are the corresponding plasma frequencies if the CC/CL were decoupled. The bulk and surface compressibilities are expressed in terms of the sound velocities $c_{b,s}$, respectively, while $c_b^2 \tau$ and $c_s^2 \tau_s$ are the corresponding diffusion coefficients. An important realization of a surface layer is the case of a charge spill-out, as in the alkali metals^{6,7,10}. In this case, the CL is further away from the restoring force provided by the equilibrium situation. Hence the equilibrium charge, when averaged over the CL thickness d in the oscillating state, is reduced and the restoring force is weak, $\omega_s < \omega_p$. Note that even with $\omega_s = 0$, there is eventually a restoring force via coupling to the bulk so that $\omega(k \rightarrow 0) = \omega_p/\sqrt{2}$. We also note that when $\omega_s = 0$, Feibelman's sum rule Eq.(1)²⁶ is still valid with $z = 0$ as origin, since the charges at $z > 0$ respond only in a nonlocal way via the gradient $\nabla \rho_s$ which affects higher order $O(k^2)$ terms. When $\omega_s \neq 0$, e.g. for nanostructures with their own ions and equilibrium charge density, the sum rule (1) is modified such that

$$B = \frac{\omega_p}{2\sqrt{2}} \left[-\frac{\int dz z \delta n(z)}{\int dz \delta n(z)} + \frac{\omega_s^2 d}{\omega_p^2} \right], \quad (3)$$

adding a positive term to the slope.

In the following we omit the damping terms ($1/\tau, 1/\tau_s$) for brevity. They are easily restored by multiplying the bulk [surface] parameters ω_p^2 and c_b^2 [ω_s^2 and c_s^2] with the factor $1 + i/(\omega\tau)$ [$1 + i/(\omega\tau_s)$], respectively.

We look for solutions to the fields at frequency ω that vary with the wave vector k parallel to the surface. Charge conservation then determines the charge profiles

$$\begin{aligned} z < 0 : \quad & [\omega_p^2 - c_b^2 \nabla^2 - \omega^2] \rho(\mathbf{r}) = 0 \\ & \Rightarrow \rho(k, z) = \rho_0(k) e^{v_b z}, \\ 0 < z < d : \quad & [\omega_s^2 - c_s^2 \nabla^2 - \omega^2] \rho_s(\mathbf{r}) = 0 \\ & \Rightarrow \rho_s(k, z) = \gamma_0(k) \cosh v_s z + \gamma_1(k) \sinh v_s z. \end{aligned} \quad (4)$$

The inverse decay lengths v_b and v_s for the bulk and surface charges are

$$\begin{aligned} v_s &= \frac{1}{c_s} \sqrt{\omega_s^2 + c_s^2 k^2 - \omega^2}, \\ v_b &= \frac{1}{c_b} \sqrt{\omega_p^2 + c_b^2 k^2 - \omega^2}. \end{aligned} \quad (5)$$

Current conservation at $z = d$ yields $(\omega_s^2/4\pi)E_z(k, d) - c_s^2 \partial_z \rho_s(k, d) = 0$, while at $z = 0$,

$$\begin{aligned} -i\omega j_z^{in} &\equiv \frac{\omega_p^2}{4\pi} E_z(k, 0^-) - c_b^2 \partial_z \rho(k, 0^-) \\ &= \frac{\omega_s^2}{4\pi} E_z(k, 0^+) - c_s^2 \partial_z \rho_s(k, 0^+) \end{aligned} \quad (6)$$

where 0^\pm denotes the limit $z \rightarrow \pm 0$.

Maxwell's equation determines the longitudinal components of \mathbf{E} in terms of the charges, however the transverse components require four unknowns: two amplitudes for upward and downward propagation in the layer, and one amplitude each in bulk ($z < 0$) and in vacuum ($z > d$). Together with the amplitudes $\rho_0, \gamma_0, \gamma_1$ for the charge density, we have seven unknowns. Each interface provides three relations (the matching of E_z , $\partial_z E_z$ and j_z), hence one boundary condition is missing. The necessity for an additional boundary condition (ABC) has a long history and occurs when more than one material mode is present, for example the γ_0, γ_1 modes of Eq. (4)²⁸⁻³¹. Therefore a microscopic input is needed to provide the ABC.

Before developing the ABC, we discuss some general properties of the CC+CL system. At very small parallel momentum, $k \lesssim \omega_p/c \sim 2 \cdot 10^{-3} \text{ \AA}^{-1}$, the SP dispersion approaches the light dispersion $\omega(k) \rightarrow ck$. While this range can be optically probed³³, most of the data is found by electron energy loss spectroscopy at higher k values. Therefore, we focus on the non-retarded region $\omega_p/c \ll k$, formally taking $c \rightarrow \infty$. Since the limit $\omega(k \rightarrow 0) = \omega_p/\sqrt{2}$ is a bulk property, we expect that the parameter ω_s has a small effect. In fact, the numerical solutions shown below confirm this for $\omega_s \lesssim 0.3 \omega_p$ and $k \lesssim 0.4 \omega_p/c_b$. Hence we display the result for $\omega_s = 0$, which has a relatively simple form:

$$\begin{aligned} \frac{c_b^2}{\omega_p^2} \rho_0(k) [v_b + \frac{\omega^2 v_b - \omega_p^2 k}{\omega^2 - \omega_p^2}] &= \\ \frac{c_s^2}{\omega^2} \gamma_0(k) [k (\frac{e^{-kd}}{\cosh v_s d} - 1) - v_s (2 \frac{\omega^2}{\omega_p^2} - 1) \tanh(v_s d)], \end{aligned} \quad (7)$$

Ref.	sample	A (eV)	B (eV·Å)	C (eV·Å ²)	Γ (eV)
6	K	2.73	−0.95	0.09	0.3
4	Ag(110) k [001]	3.76	−	3.68	0.11
4	Ag(110) k [110]	3.86	−	1.46	0.18
4	Ag(111)	3.69	−	4.17	0.06
9	0.05ML O/Ag(001)	3.71	−	3.1	~ 0.3
9	0.1ML O/Ag(001)	3.70	1.1	−0.9	~ 0.3
9	0.15ML O ₂ /Ag(001)	3.69	0.86	−0.1	~ 0.3
11	Ag(001)	3.71	1.45	−	0.15
13	Cu(111)	1.18	−0.72	−	0.2
14	10ML Ag/Ni(111)	3.75	−	1.57	~ 0.1
16	sputtered 22ML Ag/Cu(111)	3.76	−0.08	2.50	0.18
7	Mg(0001)	7.38	−3.023	9.78	1.2
10	Al(111)	10.86	−3.1	7.7	2.3

TABLE I: Data on SP dispersion $\omega = A + Bk + Ck^2$ and linewidth Γ at small k . The coefficients A, B, C are given by the corresponding references, with “−” indicating a coefficient that was assumed to be zero for the fit. All cases with $|B| > Ck_1$ or $|B| < 0.1Ck_1$ are shown with a relatively small Γ (momentum scale $k_1 = 1 \text{ Å}^{-1}$). The last two entries show cases where $0.1Ck_1 < |B| < Ck_1$ with a large Γ .

where the ABC is needed to fix the ratio $\rho_0(k)/\gamma_0(k)$. For a CC system ($\gamma_0 = 0$) we recover the well known^{1,2,25} SP dispersion $\omega^2 = \frac{1}{2}\omega_p^2 + \omega_p^2 k/2v_b$ with a dominant linear dispersion at small k , i.e.

$$\text{CC:} \quad \omega(k) = \frac{\omega_p}{\sqrt{2}} + \frac{c_b k}{2} + \mathcal{O}(k^2) \quad (8)$$

For the CL system ($\rho_0 = 0$), we obtain to lowest order as $d \rightarrow 0$ a purely quadratic dispersion $\omega^2 = \frac{1}{2}\omega_p^2 + c_s^2 k^2$, featuring the surface speed of sound c_s . Keeping d finite, and expanding for small k , we get

$$\text{CL:} \quad \omega(k) = \frac{\omega_p}{\sqrt{2}} - \frac{c_s k}{2} \tan(\bar{d}/2) + \mathcal{O}(k^2), \quad (9)$$

where $\bar{d} = \omega_p d/(\sqrt{2}c_s)$. Note the negative slope, consistent with the charge being outside the bulk ions (at $z > 0$)²⁶. The divergence at $\tan \bar{d}/2 = \infty$ corresponds to a resonant multimode response^{6,7,10,34}, which may appear at higher frequencies if the thickness d is large enough. Indeed, for $\omega_s = 0$ as assumed here, we find that this corresponds to a vanishing total layer charge, $\int_0^d dz \rho_s(k, z) = 0$: these are surface dipoles or higher multipoles. They have been observed in alkali metals^{6,7,10} where the charge response outside the bulk is significant. These modes, having larger linewidths, are not considered in the solutions below.

We note also that in order to get an acoustic plasmon solution^{2,19} with $\omega(k) \rightarrow 0$ as $k \rightarrow 0$, one would require in Eq.(7) $\gamma_0 d \rightarrow -\rho_0/v_b$ corresponding to opposite signs of the total bulk (ρ_0/v_b) and total surface ($\gamma_0 d$) charges. A specific ABC is then needed to achieve acoustic plasmons². Our model allows for surface scattering between the two types of charges, a distinct situation.

Additional boundary condition via Boltzmann equation. We proceed to derive the ABC by using a Boltzmann transport equation for the charge response^{35,36}. This approach is known to be notoriously difficult when matching conditions at an interface are involved³⁶. We have adopted an alternative approach and consider a bulk half-space terminated by a two-dimensional surface sheet that represents the charge integrated over the layer $0 < z < d$. The matching conditions are then replaced by surface scattering that mixes bulk and surface charges. At equilibrium, the bulk electron distribution per phase space $d^2 x dz d^3 p/(2\pi\hbar)^3$ is $f^0(\mathbf{x}, z, \mathbf{p})$ while the surface distribution per phase space $d^2 x d^2 q/(2\pi\hbar)^2$ is $f_s^0(\mathbf{x}, \mathbf{q})$. The surface charge sheet involves only the lateral coordinates $\mathbf{x} = (x, y)$ and a two-dimensional momentum \mathbf{q} . We note that this phase space description is possible even if the surface states are localized, by working with the Wigner transform^{37,38}. In response to a weak electric field, the distributions become $f^0 + f$, $f_s^0 + f_s$, with $f, f_s \ll 1$. The transition probability due to bulk impurity scattering per $d^3 p dt$ from state \mathbf{p} to \mathbf{p}' is $W(\mathbf{p}', \mathbf{p})$. Within the Born approximation, or more generally in the presence of time reversal and space inversion, we have $W(\mathbf{p}, \mathbf{p}') = W(\mathbf{p}', \mathbf{p})$. To 1st order in f, \mathbf{E} , with a bulk velocity $\mathbf{v}(\mathbf{p})$

$$\begin{aligned} & [\partial_t + \mathbf{v}(\mathbf{p}) \cdot \nabla] f(\mathbf{x}, z, \mathbf{p}) + e\mathbf{E} \cdot \nabla_{\mathbf{p}} f^0(\mathbf{x}, z, \mathbf{p}) \\ &= \int_{\mathbf{p}'} W(\mathbf{p}', \mathbf{p}) [f(\mathbf{x}, z, \mathbf{p}') - f(\mathbf{x}, z, \mathbf{p})] \end{aligned} \quad (10)$$

with the shorthand $\int_{\mathbf{p}'} = \int d^3 p'/(2\pi\hbar)^3$. At the surface we have a scattering cross section $W'(\mathbf{q}', \mathbf{q})$ between surface states, as well as scattering of bulk states with $p_z > 0$ into the surface ($W_s(\mathbf{q}, \mathbf{p})$) and scattering of surface states back into bulk states with $p_z < 0$ ($W_s(\mathbf{p}, \mathbf{q})$).

As in the bulk, we assume $W'(\mathbf{q}', \mathbf{q}) = W'(\mathbf{q}, \mathbf{q}')$. For $W_s(\mathbf{q}, \mathbf{p})$ we can assume reflection symmetry only in x, y as well as time reversal, hence $W_s(\mathbf{q}, \mathbf{p}) = W_s(-\mathbf{q}, -\hat{\mathbf{p}}) = W_s(\hat{\mathbf{p}}, \mathbf{q})$, where $\hat{\mathbf{p}} \equiv (p_x, p_y, -p_z)$. Boltzmann's equation, to first order in \mathbf{E} , f, f_s becomes, with a surface velocity $\mathbf{u}(\mathbf{q})$

$$\begin{aligned} & [\partial_t + \mathbf{u}(\mathbf{q}) \cdot \nabla] f_s(\mathbf{x}, \mathbf{q}) + e\mathbf{E} \cdot \nabla_{\mathbf{q}} f_s^0(\mathbf{x}, \mathbf{q}) \\ &= \int_{\mathbf{q}'} W'(\mathbf{q}', \mathbf{q}) [f_s(\mathbf{x}, \mathbf{q}') - f_s(\mathbf{x}, \mathbf{q})] \\ &+ \int_{\mathbf{p}, p_z > 0} W_s(\mathbf{q}, \mathbf{p}) \{f(\mathbf{x}, 0, \mathbf{p}) - f_s(\mathbf{x}, \mathbf{q}) \\ &+ f_s^0(\mathbf{x}, \mathbf{q}) [f(\mathbf{x}, 0, \hat{\mathbf{p}}) - f(\mathbf{x}, 0, \mathbf{p})]\} \end{aligned} \quad (11)$$

Note that unlike the bulk equation (10), f_s^0 does not cancel. The final ingredient is a matching condition: the total flux with velocity $\pm v_z$ is matched with the probability of scattering in or out of surface states. Taking $v_z > 0$ and considering the $W_s(\mathbf{q}, \mathbf{p})$ symmetries,

$$\begin{aligned} & v_z [f(\mathbf{x}, 0, \mathbf{p}) - f(\mathbf{x}, 0, \hat{\mathbf{p}})] = \\ & \int_{\mathbf{q}} W_s(\mathbf{q}, \mathbf{p}) \{f(\mathbf{x}, 0, \mathbf{p}) - f_s(\mathbf{x}, \mathbf{q}) \\ &+ f_s^0(\mathbf{x}, \mathbf{q}) [f(\mathbf{x}, 0, \hat{\mathbf{p}}) - f(\mathbf{x}, 0, \mathbf{p})]\} \end{aligned} \quad (12)$$

This relation assumes specular reflection in the absence of surface states, while the latter produce nonspecular reflection in each v_z channel. Integrating Eq.(12) over $d^3p, p_z > 0$ yields the total current incoming into the surface, $j_z^{in}(\mathbf{x})$, and by comparing with Eq.(11) integrated over d^2q , we get charge conservation at the surface

$$\partial_t \bar{\rho}_s(\mathbf{x}) + \nabla \cdot \mathbf{j}_s(\mathbf{x}) = j_z^{in}(\mathbf{x}) \quad (13)$$

where $\bar{\rho}_s(\mathbf{x}) = \int_{\mathbf{q}} f_s(\mathbf{x}, \mathbf{q})$, $\mathbf{j}_s(\mathbf{x}) = \int_{\mathbf{q}} \mathbf{u}(\mathbf{q}) f_s(\mathbf{x}, \mathbf{q})$.

To solve the transport problem, we make the P_1 approximation, i.e., on spatial scales large compared to the mean free path, only the weakest angular dependence in the momentum variable is maintained³⁹. We therefore use the following expansion

$$\begin{aligned} f(\mathbf{x}, z, \mathbf{p}) &= \rho(\mathbf{x}, z) f^{(1)}(p) + \sum_{ik} j_i(\mathbf{x}, z) v_k(\mathbf{p}) g_{ik}^{(1)}(p) \\ f_s(\mathbf{x}, \mathbf{q}) &= \bar{\rho}_s(\mathbf{x}) f_s^{(1)}(q) + \mathbf{j}_s(\mathbf{x}) \cdot \mathbf{u}(\mathbf{q}) g_s^{(1)}(q) \end{aligned} \quad (14)$$

where p, q denote the modulus of the vectors \mathbf{p}, \mathbf{q} . The reduced symmetry of the surface allows for a diagonal tensor with elements $g_{xx}^{(1)}(p) = g_{yy}^{(1)}(p) \neq g_{zz}^{(1)}(p)$. For elastic scattering, we expect the dependence on p, q to be localized near the corresponding Fermi surface, if the latter is well-defined (the surface states may be spatially localized).

Integrating the \mathbf{v} or \mathbf{u} moment of Eqs.(10,11) yields Eq.(2), identifying the plasma frequency as $\omega_p^2 = 4\pi e^2 \int_p \frac{\partial w_i}{\partial p_i} f^0(\mathbf{x}, z, \mathbf{p})$ (assuming diagonal response) which becomes $\omega_p^2 = 4\pi n e^2 / m^*$ for a parabolic dispersion with an effective mass m^* . Similarly $\omega_s^2 = 4\pi n_s e^2 / m^* d$

where n, n_s are equilibrium bulk and surface densities, respectively. The \mathbf{v} or \mathbf{u} moments of Eqs.(10,11) yield the sound velocity $c_b^2 = \int_{\mathbf{p}} v_i^2 f^{(1)}(p)$ and similarly for c_s^2 , and also identify the bulk and surface relaxation times

$$\begin{aligned} \frac{1}{\tau} &= \int_{\mathbf{p}, \mathbf{p}'} W(\mathbf{p}', \mathbf{p}) v_i^2(\mathbf{p}) g_{ii}^{(1)}(p) \\ \frac{1}{\tau_s} &= \int_{\mathbf{q}, \mathbf{q}'} W'(\mathbf{q}', \mathbf{q}) u_i^2(\mathbf{q}) g_s^{(1)}(q) \\ &+ \int_{\mathbf{p}, p_z > 0} \int_{\mathbf{q}} W_s(\mathbf{q}, \mathbf{p}) u_i^2(\mathbf{q}) g_s^{(1)}(q) \end{aligned} \quad (15)$$

where $1/\tau$ may in principle be anisotropic. We also note that the v_x moment of Eq.(12) requires in the expansion (14) of the momentum distribution a quadrupole term $f(\mathbf{x}, z, \mathbf{p}) \sim v_x v_z$. This term contributes to shear viscosity at the surface. It is of higher order in velocities, however, and does not affect the v_z moments that we discuss now.

Taking the v_z moment of the matching condition (12), we encounter the following integrals:

$$\begin{aligned} & \int_{\mathbf{p}} |v_z|^3 g_{zz}^{(1)}(p) \equiv \alpha_1 \\ & \int_{\mathbf{p}, p_z > 0} \int_{\mathbf{q}} W_s(\mathbf{q}, \mathbf{p}) v_z [\rho(\mathbf{x}, 0) f^{(1)}(p) + v_z j_z(\mathbf{x}, 0) g_{zz}^{(1)}(p)] \\ & \equiv \alpha_2 \rho(\mathbf{x}, 0) + \alpha_3 j_z(\mathbf{x}, 0) \\ & \int_{\mathbf{p}, p_z > 0} \int_{\mathbf{q}} W_s(\mathbf{q}, \mathbf{p}) v_z f_s^{(1)}(q) \equiv \alpha_4 \\ & \int_{\mathbf{p}, p_z > 0} \int_{\mathbf{q}} W_s(\mathbf{q}, \mathbf{p}) 2v_z^2 g_{zz}^{(1)}(p) f_s^0(\mathbf{x}, \mathbf{q}) \equiv \alpha_5 \end{aligned} \quad (16)$$

Note that the difference $\alpha_3 - \alpha_5$ involves an integral over $1 - 2f_s^0(\mathbf{x}, \mathbf{q})$, which vanishes if the surface states have an electron-hole symmetry.

Putting everything together, the v_z moment of Eq.(12) becomes the ABC

$$j_z^{in}(\mathbf{x}) = \alpha c_b \rho_0(\mathbf{x}) - \frac{\bar{\rho}_s(\mathbf{x})}{\tau'} \quad (17)$$

$$\alpha c_b = \frac{\alpha_2}{\alpha_1 + \alpha_3 - \alpha_5} \quad (18)$$

$$\frac{1}{\tau'} = \frac{\alpha_4}{\alpha_1 + \alpha_3 - \alpha_5} \quad (19)$$

The two coefficients on the rhs can be interpreted as a probability of a bulk carrier getting trapped in a surface state (coefficient α) and a desorption rate back into the bulk (rate $1/\tau'$).

Solutions for the dispersion relation. To make contact with the electromagnetic calculation, we identify $\bar{\rho}_s$ with the charge density averaged over the layer $0 < z < d$, i.e., integrating Eq.(2), we get $\bar{\rho}_s(k) = [\gamma_0(k) \sinh v_s d - \gamma_1(k)(1 - \cosh v_s d)]/v_s$. When the boundary condition for the electric field E_z and Eq.(6) for the current j_z^{in} flowing into the layer, are combined with the ABC (17), one gets a linear system for the charge

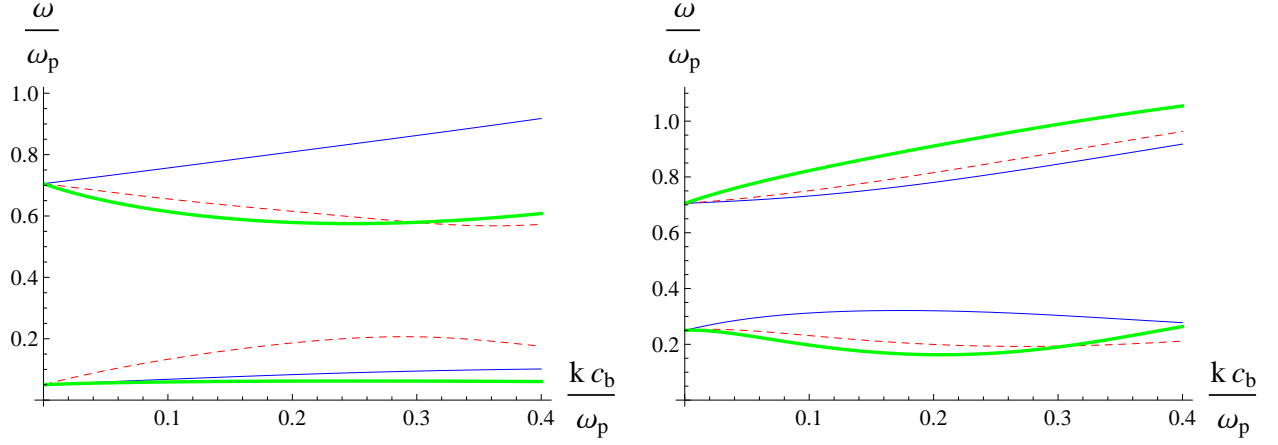


FIG. 1: (left) Surface plasmon dispersion relation $\omega(k)$ for different values of the surface scattering parameter α in Eq.(17): $\alpha = 0.1$ (thin blue lines), $\alpha = 1$ (dashed red lines) and $\alpha = 10$ (thick green lines). Upper lines starting at $\omega_p/\sqrt{2}$: real part; lower lines: imaginary part $\times (-1)$. Other parameters: $\omega_s = 0$, $c_s/c_b = 1$, $\omega_p\tau = 10$, $\omega_p\tau_s = 10$, $\tau' = \infty$ and $\tilde{d} = \omega_p d/c_b = 3.5$. (right) Effects of a nonzero restoring force in the surface layer (plasma frequency ω_s): $\omega_s = 0$ (thin blue curves), $\omega_s/\omega_p = 0.5$ (dashed red curves) and $\omega_s/\omega_p = 0.9$ (thick green curves). The upper curves are the real part and the lower ones are the imaginary part $\times (-5)$. The other parameters are $c_s/c_b = \sqrt{3}$, $\omega_p\tau = 10$, $\omega_p\tau_s = 10$, $\tau'\omega_p = 1$, $\alpha = 0.1$ and $\tilde{d} = 7$.

amplitudes $\rho_0(k)$, $\gamma_0(k)$, $\gamma_1(k)$. For the interesting case $\omega_s = 0$, this becomes

$$\alpha c_b \rho_0(k) = \left[i \frac{c_s^2 k^2 - \omega^2}{\omega} + \frac{1}{\tau'} \frac{\tanh v_s d}{v_s} \right] \gamma_0(k) \quad (20)$$

and with Eq.(7) yields the SP dispersion

$$c_b \frac{v_b(2\omega^2 - \omega_p^2) - \omega_p^2 k}{\omega^2 - \omega_p^2} = \frac{i\alpha}{\omega} \frac{c_s^2 \omega_p^2}{\omega^2 - c_s^2 k^2 + i\omega/\tau'} \times \left[v_s k \left(\frac{e^{-kd}}{\sinh v_s d} - \frac{1}{\tanh v_s d} \right) - v_s^2 \left(2 \frac{\omega^2}{\omega_p^2} - 1 \right) \right] \quad (21)$$

The parameter α thus measures the relative importance of the CC and CL amplitudes. For $\alpha \ll 1$, the dispersion corresponds to a CC oscillation, Eq.(8), while for $\alpha \gg 1$ the dispersion is dominated by the CL, Eq.(9). We recall that a large value of α is facilitated when electron-hole symmetry holds [$\alpha_3 = \alpha_5$ in Eq.(18)].

We display in Fig.1 numerical solutions for the SP dispersion. On the left the effect of the CC/CL mixing parameter α is shown: the linewidth is relatively small for $\alpha = 0.1$ (dominant CC) or $\alpha = 10$ (dominant CL), while it is much larger for $\alpha = 1$ corresponding to strong CC/CL mixing. This figure is for $\tilde{d} = \omega_p d/c_b = 3.5$ demonstrating also a negative initial slope when the CL is significant, i.e. $\alpha = 1, 10$. When d is smaller, maintaining $\alpha > 1$, the linear term is suppressed (Eq. 1) and the dispersion becomes purely parabolic, as observed in some cases^{4,9,14}. Fig.1(right) demonstrates the effect of ω_s and the possibility of generating a local minimum in $\Gamma(k)$, as observed in some cases^{10,12}. This situation is facilitated by $\omega_s \approx \omega_p$ and $\tau'\omega_p = 1$, $\tilde{d} = 7$. The effect of ω_s on the real part is to increase the linear term in k , as discussed in Eq.(3).

Discussion. We developed here a general scheme for solving the SP dispersion at low k , allowing for two charge types, CC and CL, both with nonlocal diffusive response. We have solved the notorious ABC problem by a Boltzmann equation that allows for CC/CL surface scattering. The resulting dispersion is consistent with a large variety of data accumulated on pure metals (where the CL corresponds to the spill-out charge), on sputtered systems, disordered surfaces, quantum well surface states, all leading to distinct electron states in a surface layer.

We discuss now the role of the most significant parameters: surface mixing α , layer thickness d , surface restoring force ω_s^2 , and how they correspond to observed data. Consider first the surface mixing: when it is weak (small or large α), it leads to a relatively small linewidth as in the first eleven lines of Table I. Weak surface mixing corresponds also to dominant CC or CL which is realized e.g. when the dispersion is dominantly linear or quadratic, as indeed in those eleven lines. Cases where the linear and quadratic terms are comparable may (last two lines of Table I) or may not lead to a large linewidth. In the latter case a detailed fit is necessary, and is also demonstrated in Fig. 1(left).

The layer thickness d allows for a negative linear dispersion, as seen in many metals (Table I). When $d \rightarrow 0$ and CL dominates ($\alpha \gg 1$), the dispersion is purely quadratic, as indeed seen in several cases^{4,9,14}.

The surface restoring force ω_s is expected to be small, $\omega_s < \omega_p$, in the case of alkali metals where the spill-out charge is further away from the equilibrium charges. In other cases, a large ω_s shows the peculiar feature of a minimum in $\Gamma(k)$, as demonstrated in Fig.1(right). This minimum, as Al(111)¹⁰ and Ag on Si(111)¹², has

been discussed in terms of specific band structures. Our approach is an alternative description in terms of the charge distribution. With a few parameters our model is thus able to describe SP dispersion and linewidth on a large variety of metals and surfaces, as seen over the last decades.

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